Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-279-6375

#### Inclosure Material:

Glass

# **Overall Length:**

Between 0.140 inches and 0.185 inches

# **Terminal Length:**

Between 1.000 inches and 1.300 inches

## **Overall Diameter:**

Between 0.085 inches and 0.140 inches

#### **Function For Which Designed:**

Transient suppressor

#### Mounting Method:

Terminal

#### Features Provided:

Quality assurance level txv

#### **Semiconductor Material:**

Silicon

#### Voltage Rating In Volts Per Characteristic:

8.65 breakdown voltage, instantaneous and 9.55 breakdown voltage, instantaneous

## Voltage Tolerance In Percent:

-5.0/+5.0

## **Current Rating Per Characteristic:**

150.00 milliamperes collector current, dc torr and 20.00 microamperes forward current, average peak

### **Power Rating Per Characteristic:**

2.0 watts small-signal input power, common-collector major

### Maximum Operating Tempurature Per Measurement Point:

175.0 degrees celsius ambient air

### **Test Data Document:**

81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.).

### Terminal Type And Quantity:

2 uninsulated wire lead

#### **Specification Data:**

81349-mil-s-19500/516 government specification

#### Shelf Life:

N/a

#### Unit Of Measure:

--

## Demilitarization:

No

Fiig:

A110a0